

2SC4964

Silicon NPN Epitaxial

REJ03G0736-0300 (Previous ADE-208-005A) Rev.3.00 Aug.10.2005

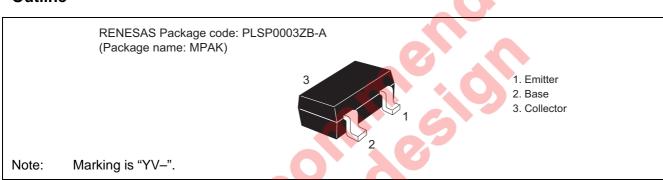
Application

VHF / UHF RF switch

Features

- Low Ron and high performance for RF switch.
- Capable of high density mounting.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	12	V
Collector to emitter voltage	V_{CEO}	8	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	Ic	100	mA
Collector power dissipation	Pc	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

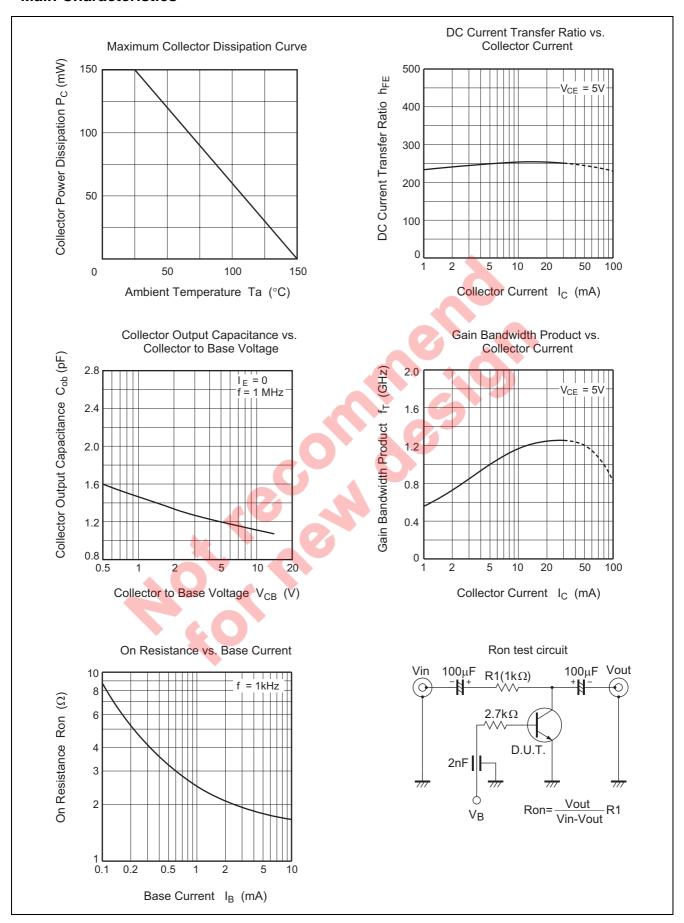
Electrical Characteristics

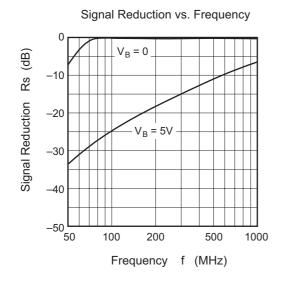
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	12	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector cutoff current	I _{CBO}	_	_	1	μΑ	$V_{CB} = 10 \text{ V}, I_{E} = 0$
	I _{CEO}	_	_	1	mA	V _{CE} = 8 V, R _{BE} = ∞
Emitter cutoff current	I _{EBO}	_	_	10	μΑ	$V_{EB} = 3 \text{ V}, I_{C} = 0$
DC current transfer ratio	h _{FE}	100	250	600		$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	200	300	mV	$I_C = 80 \text{ mA}, I_B = 5 \text{ mA}$
Collector output capacitance	Cob		1.2	1.6	pF	$V_{CB} = 5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$
On resistance	Ron	_	2.0	_	Ω	$I_B = 2.5 \text{ mA}, f = 1 \text{ kHz}$



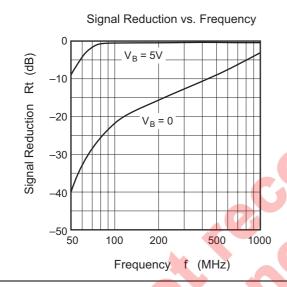
Main Characteristics

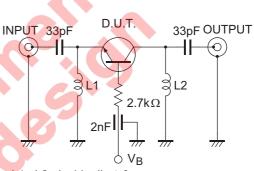




Signal Reduction test circuit INPUT 33pF 33pF OUTPUT 2.7kΩ D.U.T. VB

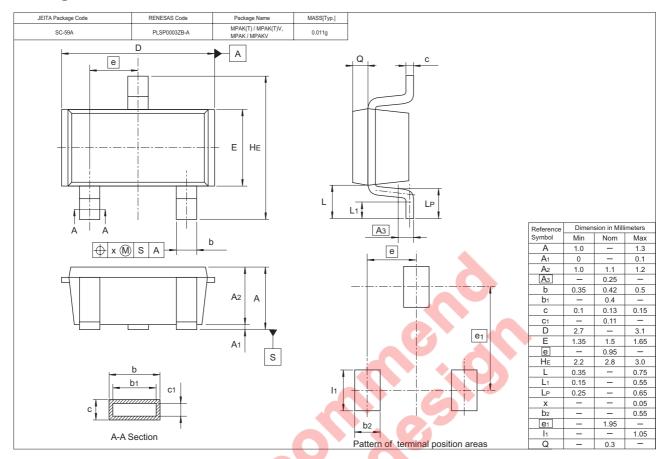
L1 : Inside dia ϕ 3 mm , $\phi~0.5~mm~Enameled~Copper~Wire~7~Turns.$





Signal Reduction test circuit

Package Dimensions



Ordering Information

Part Name	Quantity		Shipping Container
2SC4964YV-TL-E	3000	φ ′	78 mm Reel, 8 mm Emboss Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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